MC74HC374A

Octal 3-State Non-Inverting D Flip-Flop

### High−Performance Silicon−Gate CMOS

The MC74HC374A is identical in pinout to the LS374. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

Data meeting the setup time is clocked to the outputs with the rising edge of the clock. The Output Enable input does not affect the states of the flip−flops, but when Output Enable is high, the outputs are forced to the high−impedance state; thus, data may be stored even when the outputs are not enabled.

The HC374A is identical in function to the HC574A which has the input pins on the opposite side of the package from the output. This device is similar in function to the HC534A which has inverting outputs.
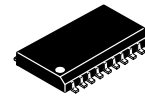
Features

- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 μA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7 A
- Chip Complexity: 266 FETs or 66.5 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
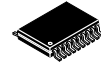- These Devices are Pb−Free and are RoHS Compliant
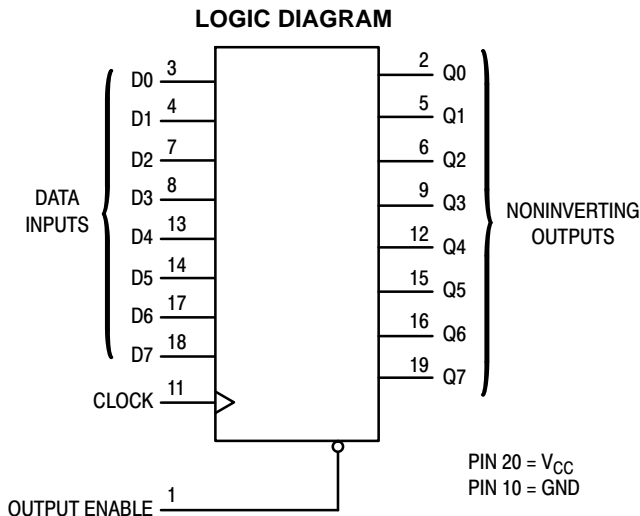
ON Semiconductor®
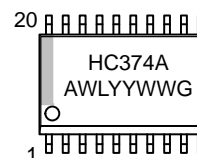
www.onsemi.com

SOIC−20
DW SUFFIX
CASE 751D

TSSOP−20
DT SUFFIX
CASE 948E
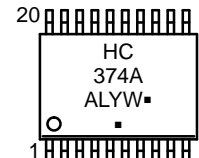
PIN ASSIGNMENT

OUTPUT ENABLE	1●	20	V_CC
Q0	2	19	Q7
D0	3	18	D7
D1	4	17	D6
Q1	5	16	Q6
Q2	6	15	Q5
D2	7	14	D5
D3	8	13	D4
Q3	9	12	Q4
GND	10	11	CLOCK

MARKING DIAGRAMS

SOIC−20

HC374A
AWLYYWWG

TSSOP−20

HC
374A
ALYW■

A	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week
G or ■	= Pb−Free Package

(Note: Microdot may be in either location)

FUNCTION TABLE

Inputs			Output
Output Enable	Clock	D	Q
L	⌐	H	H
L	⌐	L	L
L	L,H,⌐	X	No Change
H	X	X	Z

X = don't care
Z = high impedance

LOGIC DIAGRAM

DATA INPUTS: D0 (3), D1 (4), D2 (7), D3 (8), D4 (13), D5 (14), D6 (17), D7 (18), CLOCK (11)

NONINVERTING OUTPUTS: Q0 (2), Q1 (5), Q2 (6), Q3 (9), Q4 (12), Q5 (15), Q6 (16), Q7 (19)

OUTPUT ENABLE (1)

PIN 20 = V_CC
PIN 10 = GND

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MC74HC374A

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	−0.5 to +7.0	V
V_{in}	DC Input Voltage (Referenced to GND)	−0.5 to V_{CC} + 0.5	V
V_{out}	DC Output Voltage (Referenced to GND)	−0.5 to V_{CC} + 0.5	V
I_{in}	DC Input Current, per Pin	±20	mA
I_{out}	DC Output Current, per Pin	±35	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	±75	mA
P_D	Power Dissipation in Still Air, SOIC Package† TSSOP Package†	500 450	mW
T_{stg}	Storage Temperature	−65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds (SOIC, SSOP or TSSOP Package)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
†Derating: SOIC Package: −7 mW/°C from 65° to 125°C
    TSSOP Package: −6.1 mW/°C from 65° to 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high−impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}.
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)		2.0	6.0	V
V_{in}, V_{out}	DC Input Voltage, Output Voltage (Referenced to GND)		0	V_{CC}	V
T_A	Operating Temperature, All Package Types		−55	+125	°C
t_r, t_f	Input Rise and Fall Time (Figure 1)	V_{CC} = 2.0 V V_{CC} = 4.5 V V_{CC} = 6.0 V	0 0 0	1000 500 400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit −55 to 25°C	≤ 85°C	≤ 125°C	Unit
V_{IH}	Minimum High−Level Input Voltage	V_{out} = 0.1 V or V_{CC} − 0.1 V |I_{out}| ≤ 20 μA	2.0 3.0 4.5 6.0	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	V
V_{IL}	Maximum Low−Level Input Voltage	V_{out} = 0.1 V or V_{CC} − 0.1 V |I_{out}| ≤ 20 μA	2.0 3.0 4.5 6.0	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	V
V_{OH}	Minimum High−Level Output Voltage	V_{in} = V_{IH} or V_{IL} |I_{out}| ≤ 20 μA	2.0 4.5 6.0	1.90 4.40 5.90	1.90 4.40 5.90	1.90 4.40 5.90	V
		V_{in} = V_{IH} or V_{IL} |I_{out}| ≤ 2.4 mA |I_{out}| ≤ 6.0 mA |I_{out}| ≤ 7.8 mA	3.0 4.5 6.0	2.48 2.98 5.48	2.34 3.84 5.34	2.20 3.70 5.20	V
V_{OL}	Maximum Low−Level Output Voltage	V_{in} = V_{IH} or V_{IL} |I_{out}| ≤ 20 μA	2.0 4.5 6.0	0.10 0.10 0.10	0.10 0.10 0.10	0.10 0.10 0.10	V
		V_{in} = V_{IH} or V_{IL} |I_{out}| ≤ 2.4 mA |I_{out}| ≤ 6.0 mA |I_{out}| ≤ 7.8 mA	3.0 4.5 6.0	0.26 0.26 0.26	0.33 0.33 0.33	0.40 0.40 0.40	V
I_{in}	Maximum Input Leakage Current	V_{in} = V_{CC} or GND	6.0	±0.1	±1.0	±1.0	μA

MC74HC374A

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND) (continued)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				−55 to 25°C	≤ 85°C	≤ 125°C	
I_{OZ}	Maximum Three−State Leakage Current	Output in High−Impedance State $V_{in} = V_{IL}$ or V_{IH} $V_{out} = V_{CC}$ or GND	6.0	±0.5	±5.0	±10	µA
I_{CC}	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC}$ or GND $I_{out} = 0$ µA	6.0	4	40	160	µA

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input $t_r = t_f$ = 6.0 ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			−55 to 25°C	≤ 85°C	≤ 125°C	
f_{max}	Maximum Clock Frequency (50% Duty Cycle)	2.0 3.0 4.5 6.0	6 15 30 35	5 10 24 28	4 8 20 24	MHz
t_{PLH} t_{PHL}	Maximum Propagation Delay, Input Clock to Q (Figures 1 and 5)	2.0 3.0 4.5 6.0	125 80 25 21	155 110 31 26	190 130 38 32	ns
t_{PLZ} t_{PHZ}	Maximum Propagation Delay, Output Enable to Q (Figures 3 and 6)	2.0 3.0 4.5 6.0	150 100 30 26	190 125 38 33	225 150 45 38	ns
t_{PZL} t_{PZH}	Maximum Propagation Delay, Output Enable to Q (Figures 3 and 6)	2.0 3.0 4.5 6.0	150 100 30 26	190 125 38 33	225 150 45 38	ns
t_{TLH} t_{THL}	Maximum Output Transition Time, Any Output (Figures 1 and 5)	2.0 3.0 4.5 6.0	75 27 15 13	95 32 19 16	110 36 22 19	ns
C_{in}	Maximum Input Capacitance		10	10	10	pF
C_{out}	Maximum Three−State Output Capacitance (Output in High−Impedance State)		15	15	15	pF

Symbol	Parameter	Typical @ 25°C, V_{CC} = 5.0 V	Unit
C_{PD}	Power Dissipation Capacitance (Per Enabled Output)*	34	pF

* Used to determine the no−load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

MC74HC374A

| Symbol | Parameter | Figure | V_{CC} Volts | Guaranteed Limit | | | | | | Unit |
| | | | | −55 to 25°C | | ≤ 85°C | | ≤ 125°C | | |
				Min	Max	Min	Max	Min	Max	
t_{su}	Minimum Setup Time, Data to Clock	3	2.0	50		65		75		ns
			3.0	40		50		60		
			4.5	10		13		15		
			6.0	9		11		13		
t_h	Minimum Hold Time, Clock to Data	3	2.0	5.0		5.0		5.0		ns
			3.0	5.0		5 0		5.0		
			4.5	5.0		5.0		5.0		
			6.0	5.0		5.0		5.0		
t_w	Minimum Pulse Width, Clock	1	2.0	60		75		90		ns
			3.0	23		27		32		
			4.5	12		15		18		
			6.0	10		13		15		
t_r, t_f	Maximum Input Rise and Fall Times	1	2.0		1000		1000		1000	ns
			3.0		800		800		800	
			4.5		500		500		500	
			6.0		400		400		400	

SWITCHING WAVEFORMS
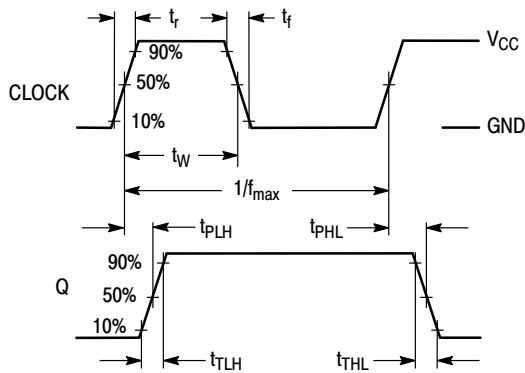
Figure 1.
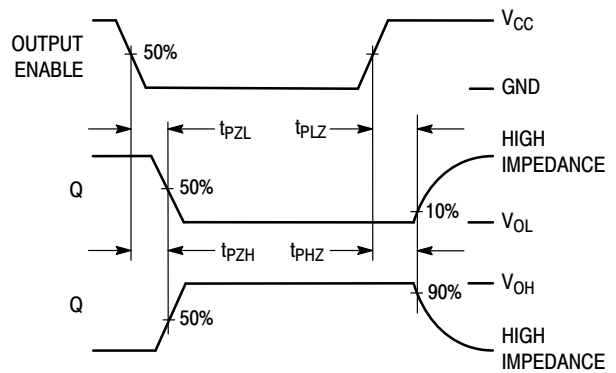
Figure 2.
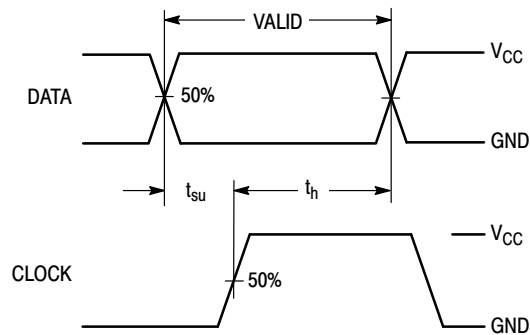
Figure 3.
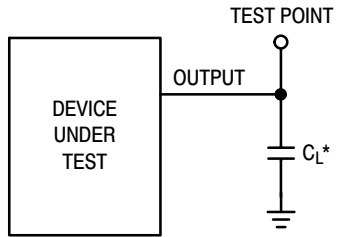
TEST CIRCUITS

*Includes all probe and jig capacitance

Figure 4.

CONNECT TO V_{CC} WHEN TESTING t_{PLZ} AND t_{PZL}. CONNECT TO GND WHEN TESTING t_{PHZ} AND t_{PZH}.
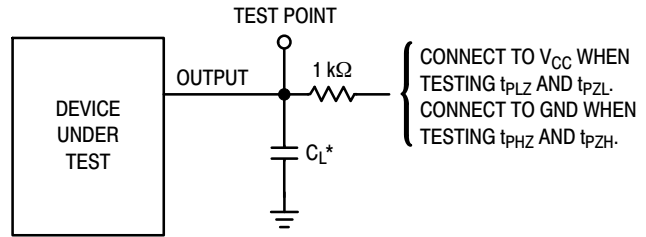
*Includes all probe and jig capacitance
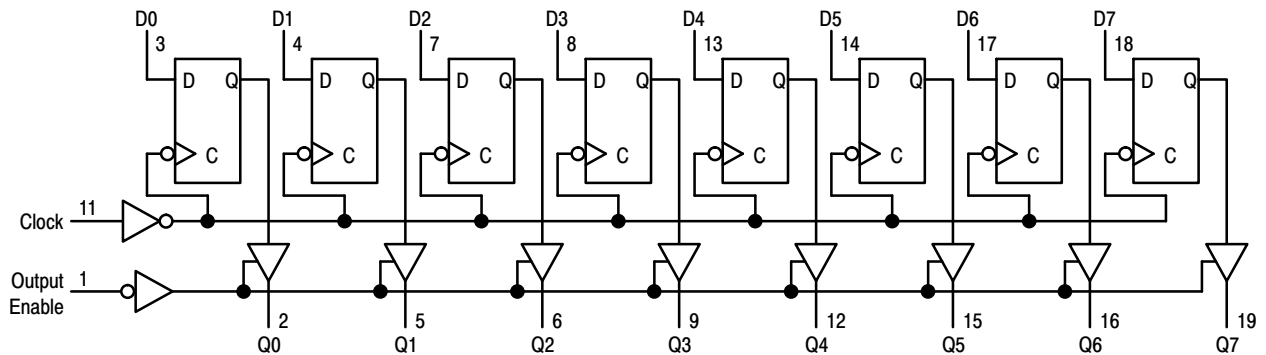
Figure 5.

Figure 6. Expanded Logic Diagram

ORDERING INFORMATION

Device	Package	Shipping†
MC74HC374ADWG	SOIC−20 WIDE (Pb−Free)	38 Units / Rail
NLV74HC374ADWG*	SOIC−20 WIDE (Pb−Free)	38 Units / Rail
MC74HC374ADWR2G	SOIC−20 WIDE (Pb−Free)	1000 Tape & Reel
NLV74HC374ADWR2G*	SOIC−20 WIDE (Pb−Free)	1000 Tape & Reel
MC74HC374ADTG	TSSOP−20 (Pb−Free)	75 Units / Rail
MC74HC374ADTR2G	TSSOP−20 (Pb−Free)	2500 Tape & Reel
NLV74HC374ADTR2G*	TSSOP−20 (Pb−Free)	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

SOIC−20 WB
CASE 751D−05
ISSUE H

DATE 22 APR 2015

SCALE 1:1

NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
---	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0 °	7 °

RECOMMENDED SOLDERING FOOTPRINT*

20X 0.52
20X 1.30
11.00
1.27 PITCH
DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*

XXXXXXXXXX
XXXXXXXXXX
AWLYYWWG
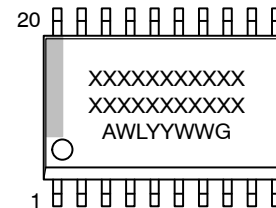
XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98ASB42343B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOIC−20 WB		PAGE 1 OF 1

TSSOP−20 WB
CASE 948E
ISSUE D

DATE 17 FEB 2016

SCALE 2:1

20X **K** REF

⊕ | 0.15 (0.006) | T | U | Ⓢ

⊕ | 0.10 (0.004) | Ⓜ | T | U | Ⓢ | V | Ⓢ

2X **L/2**

L

PIN 1 IDENT

20   11

B

−U−

10

⊕ | 0.15 (0.006) | T | U | Ⓢ

A

−V−

K
K1

J **J1**

SECTION N−N

0.25 (0.010)

N

M

N

F

DETAIL E

C

D → **G** ← **H**

△ | 0.100 (0.004)

−T− **SEATING PLANE**

−W−

DETAIL E

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

SOLDERING FOOTPRINT

7.06

1

0.65
PITCH

16X
0.36

16X
1.26

DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*

XXXX
XXXX
ALYW■

A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
■ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot " ■ ", may or may not be present.

DOCUMENT NUMBER:	98ASH70169A	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TSSOP−20 WB		PAGE 1 OF 1

PUBLICATION ORDERING INFORMATION

◊